

MC1776C

Micropower Programmable Operational Amplifier

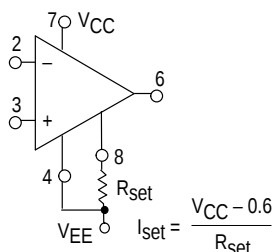
This extremely versatile operational amplifier features low power consumption and high input impedance. In addition, the quiescent currents within the device may be programmed by the choice of an external resistor value or current source applied to the I_{set} input. This allows the amplifier's characteristics to be optimized for input current and power consumption despite wide variations in operating power supply voltages.

- ± 1.2 V to ± 18 V Operation
- Wide Programming Range
- Offset Null Capability
- No Frequency Compensation Required
- Low Input Bias Currents
- Short Circuit Protection

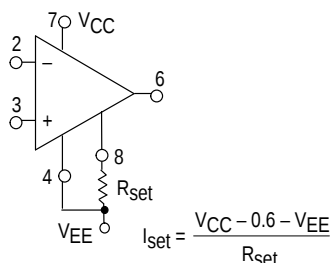
Resistive Programming

(See Figure 1)

R_{set} to Ground



R_{set} to Negative Supply

(Recommended for supply voltage less than ± 6.0 V)


Typical R_{set} Values

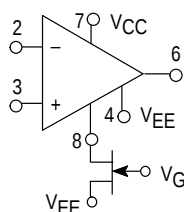
V_{CC}, V_{EE}	$I_{set} = 1.5 \mu A$	$I_{set} = 15 \mu A$
± 6.0 V	3.6 M Ω	360 k Ω
± 10 V	6.2 M Ω	620 k Ω
± 12 V	7.5 M Ω	750 k Ω
± 15 V	10 M Ω	1.0 M Ω

Typical R_{set} Values

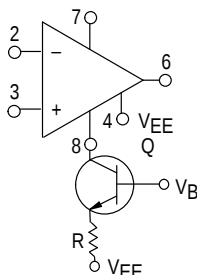
V_{CC}, V_{EE}	$I_{set} = 1.5 \mu A$	$I_{set} = 15 \mu A$
± 1.5 V	1.6 M Ω	160 k Ω
± 3.0 V	3.6 M Ω	360 k Ω
± 6.0 V	7.5 M Ω	750 k Ω
± 15 V	20 M Ω	2.0 M Ω

Active Programming

FET Current Source



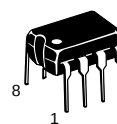
Bipolar Current Source



Pins not shown are not connected.

PROGRAMMABLE OPERATIONAL AMPLIFIER

SEMICONDUCTOR TECHNICAL DATA

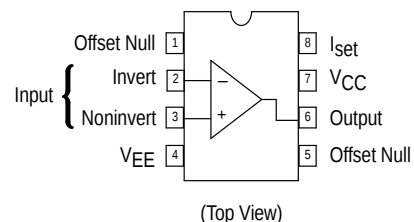


P1 SUFFIX
PLASTIC PACKAGE
CASE 626



D SUFFIX
PLASTIC PACKAGE
CASE 751
(SO-8)

PIN CONNECTIONS



ORDERING INFORMATION

Device	Operating Temperature Range	Package
MC1776CD	$T_A = 0^\circ$ to $+70^\circ C$	SO-8
MC1776CP1		Plastic DIP

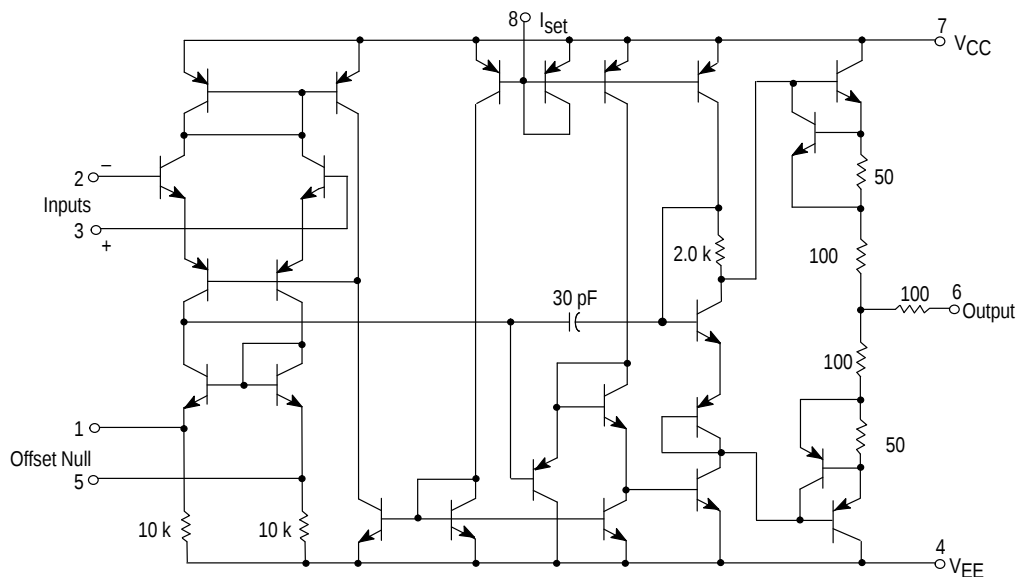
MC1776C

MAXIMUM RATINGS (T_A = +25°C, unless otherwise noted.)

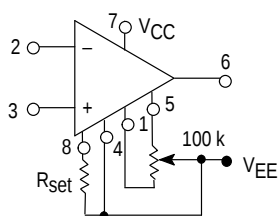
Rating	Symbol	Value	Unit
Power Supply Voltages	V_{CC}, V_{EE}	± 18	Vdc
Differential Input Voltage	V_{ID}	± 30	Vdc
Common Mode Input Voltage V_{CC} and $ V_{EE} < 15$ V V_{CC} and $ V_{EE} \geq 15$ V	V_{ICM}	V_{CC}, V_{EE} ± 15	Vdc
Offset Null to V_{EE} Voltage	$V_{off} - V_{EE}$	± 0.5	Vdc
Programming Current	I_{set}	500	μ A
Programming Voltage (Voltage from I_{set} Terminal to Ground)	V_{set}	($V_{CC} - 2.0$ V) to V_{CC}	Vdc
Output Short Circuit Duration (Note 1)	t_{SC}	Indefinite	sec
Operating Temperature Range	T_A	0 to +70	$^{\circ}$ C
Storage Temperature Range	T_{stg}	-65 to +150	$^{\circ}$ C
Junction Temperature	T_J	150	$^{\circ}$ C

NOTE 1. May be to ground or either supply voltage. Rating applies up to a case temperature of +125°C or ambient temperature of +70°C and $I_{set} \leq 30 \mu A$.

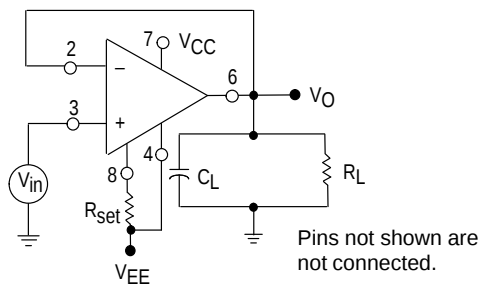
Representative Schematic Diagram



Voltage Offset Null Circuit



Transient Response Test Circuit



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ELECTRICAL CHARACTERISTICS ($V_{CC} = +3.0\text{ V}$, $V_{EE} = -3.0\text{ V}$, $I_{Set} = 1.5\text{ }\mu\text{A}$, $T_A = +25^\circ\text{C}$, unless otherwise noted.*)

Characteristic	Symbol	Min	Typ	Max	Unit
Input Offset Voltage ($R_S \leq 10\text{ k}\Omega$) $T_A = +25^\circ\text{C}$ $T_{low}^* \leq T_A \leq T_{high}^*$	V_{IO}	– –	2.0 –	6.0 7.5	mV
Offset Voltage Adjustment Range	V_{IOR}	–	9.0	–	mV
Input Offset Current $T_A = +25^\circ\text{C}$ $T_A = T_{high}$ $T_A = T_{low}$	I_{IO}	– – –	0.7 – –	6.0 6.0 10	nA
Input Bias Current $T_A = +25^\circ\text{C}$ $T_A = T_{high}$ $T_A = T_{low}$	I_{IB}	– – –	2.0 – –	10 10 20	nA
Input Resistance	r_i	–	50	–	M Ω
Input Capacitance	c_i	–	2.0	–	pF
Input Voltage Range $T_{low} \leq T_A \leq T_{high}$	V_{ID}	+1.0	–	–	V
Large Signal Voltage Gain $R_L \geq 75\text{ k}\Omega$, $V_O = \pm 1.0\text{ V}$, $T_A = +25^\circ\text{C}$ $R_L \geq 75\text{ k}\Omega$, $V_O = \pm 1.0\text{ V}$, $T_{low} \leq T_A \leq T_{high}$	A_{VOL}	25 k 25 k	200 k –	– –	V/V
Output Voltage Swing $R_L \geq 75\text{ k}\Omega$, $T_{low} \leq T_A \leq T_{high}$	V_O	± 2.0	± 2.4	–	V
Output Resistance	r_o	–	5.0	–	k Ω
Output Short Circuit Current	I_{SC}	–	3.0	–	mA
Common Mode Rejection $R_S \leq 10\text{ k}\Omega$, $T_{low} \leq T_A \leq T_{high}$	CMR	70	86	–	dB
Supply Voltage Rejection Ratio $R_S \leq 10\text{ k}\Omega$, $T_{low} \leq T_A \leq T_{high}$	PSRR	–	25	200	$\mu\text{V/V}$
Supply Current $T_A = +25^\circ\text{C}$ $T_{low} \leq T_A \leq T_{high}$	I_{CC} , I_{EE}	– –	13 –	20 25	μA
Power Dissipation $T_A = +25^\circ\text{C}$ $T_{low} \leq T_A \leq T_{high}$	P_D	– –	78 –	120 150	μW
Transient Response (Unity Gain) $V_{in} = 20\text{ mV}$, $R_L \geq 5.0\text{ k}\Omega$, $C_L = 100\text{ pF}$ Rise Time Overshoot	t_{TLH} t_{OS}	– –	3.0 0	– –	μs %
Slew Rate ($R_L \geq 5.0\text{ k}\Omega$)	S_R	–	0.03	–	V/ μs

* $T_{low} = 0^\circ\text{C}$ $T_{high} = +70^\circ\text{C}$

MC1776C

ELECTRICAL CHARACTERISTICS ($V_{CC} = +3.0\text{ V}$, $V_{EE} = -3.0\text{ V}$, $I_{Set} = 15\text{ }\mu\text{A}$, $T_A = +25^\circ\text{C}$, unless otherwise noted.)*

Characteristic	Symbol	Min	Typ	Max	Unit
Input Offset Voltage ($R_S \leq 10\text{ k}\Omega$) $T_A = +25^\circ\text{C}$ $T_{low}^* \leq T_A \leq T_{high}^*$	V_{IO}	— —	2.0 —	6.0 7.5	mV
Offset Voltage Adjustment Range	V_{IOR}	—	18	—	mV
Input Offset Current $T_A = +25^\circ\text{C}$ $T_A = T_{high}$ $T_A = T_{low}$	I_{IO}	— — —	2.0 — —	25 25 40	nA
Input Bias Current $T_A = +25^\circ\text{C}$ $T_A = T_{high}$ $T_A = T_{low}$	I_{IB}	— — —	15 — —	50 50 100	nA
Input Resistance	r_i	—	5.0	—	M Ω
Input Capacitance	c_i	—	2.0	—	pF
Input Voltage Range $T_{low} \leq T_A \leq T_{high}$	V_{ID}	± 1.0	—	—	V
Large Signal Voltage Gain $R_L \geq 5.0\text{ k}\Omega$, $V_O = \pm 1.0\text{ V}$, $T_A = +25^\circ\text{C}$ $R_L \geq 5.0\text{ k}\Omega$, $V_O = \pm 1.0\text{ V}$, $T_{low} \leq T_A \leq T_{high}$	A_{VOL}	25 k 25 k	200 k —	— —	V/V
Output Voltage Swing $R_L \geq 5.0\text{ k}\Omega$, $T_{low} \leq T_A \leq T_{high}$	V_O	± 2.0	± 2.1	—	V
Output Resistance	r_o	—	1.0	—	k Ω
Output Short Circuit Current	I_{SC}	—	5.0	—	mA
Common Mode Rejection $R_S \leq 10\text{ k}\Omega$, $T_{low} \leq T_A \leq T_{high}$	CMR	70	86	—	dB
Supply Voltage Rejection Ratio $R_S \leq 10\text{ k}\Omega$, $T_{low} \leq T_A \leq T_{high}$	PSRR	—	25	200	$\mu\text{V/V}$
Supply Current $T_A = +25^\circ\text{C}$ $T_{low} \leq T_A \leq T_{high}$	I_{CC} , I_{EE}	— —	130 —	170 180	μA
Power Dissipation $T_A = +25^\circ\text{C}$ $T_{low} \leq T_A \leq T_{high}$	P_D	— —	780 —	1020 1080	μW
Transient Response (Unity Gain) $V_{in} = 20\text{ mV}$, $R_L \geq 5.0\text{ k}\Omega$, $C_L = 100\text{ pF}$ Rise Time Overshoot	t_{TLH} os	— —	0.6 5.0	— —	μs %
Slew Rate ($R_L \geq 5.0\text{ k}\Omega$)	S_R	—	0.35	—	V/ μs

* $T_{low} = 0^\circ\text{C}$ $T_{high} = +70^\circ\text{C}$

MC1776C

ELECTRICAL CHARACTERISTICS ($V_{CC} = +15\text{ V}$, $V_{EE} = -15\text{ V}$, $I_{set} = 1.5\text{ }\mu\text{A}$, $T_A = +25^\circ\text{C}$, unless otherwise noted.*)

Characteristic	Symbol	Min	Typ	Max	Unit
Input Offset Voltage ($R_S \leq 10\text{ k}\Omega$) $T_A = +25^\circ\text{C}$ $T_{low}^* \leq T_A \leq T_{high}^*$	V_{IO}	— —	2.0 —	6.0 7.5	mV
Offset Voltage Adjustment Range	V_{IOR}	—	9.0	—	mV
Input Offset Current $T_A = +25^\circ\text{C}$ $T_A = T_{high}$ $T_A = T_{low}$	I_{IO}	— — —	0.7 — —	6.0 6.0 10	nA
Input Bias Current $T_A = +25^\circ\text{C}$ $T_A = T_{high}$ $T_A = T_{low}$	I_{IB}	— — —	2.0 — —	10 10 20	nA
Input Resistance	r_i	—	50	—	$M\Omega$
Input Capacitance	c_i	—	2.0	—	pF
Input Voltage Range $T_{low} \leq T_A \leq T_{high}$	V_{ID}	± 10	—	—	V
Large Signal Voltage Gain $R_L \geq 75\text{ k}\Omega$, $V_O = \pm 10\text{ V}$, $T_A = +25^\circ\text{C}$ $R_L \geq 75\text{ k}\Omega$, $V_O = \pm 10\text{ V}$, $T_{low} \leq T_A \leq T_{high}$	A_{VOL}	50 k 50 k	400 k —	— —	V/V
Output Voltage Swing $R_L \geq 75\text{ k}\Omega$, $T_A = +25^\circ\text{C}$ $R_L \geq 75\text{ k}\Omega$, $T_{low} \leq T_A \leq T_{high}$	V_O	± 12 ± 10	± 14 —	— —	V
Output Resistance	r_o	—	5.0	—	$k\Omega$
Output Short Circuit Current	I_{SC}	—	3.0	—	mA
Common Mode Rejection $R_S \leq 10\text{ k}\Omega$, $T_{low} \leq T_A \leq T_{high}$	CMR	70	90	—	dB
Supply Voltage Rejection Ratio $R_S \leq 10\text{ k}\Omega$, $T_{low} \leq T_A \leq T_{high}$	PSRR	—	25	200	$\mu\text{V/V}$
Supply Current $T_A = +25^\circ\text{C}$ $T_{low} \leq T_A \leq T_{high}$	I_{CC} , I_{EE}	— —	20 —	30 35	μA
Power Dissipation $T_A = +25^\circ\text{C}$ $T_{low} \leq T_A \leq T_{high}$	P_D	— —	780 —	0.9 1.05	mW
Transient Response (Unity Gain) $V_{in} = 20\text{ mV}$, $R_L \geq 5.0\text{ k}\Omega$, $C_L = 100\text{ pF}$ Rise Time Overshoot	t_{TLH} t_{os}	— —	1.6 0	— —	μs %
Slew Rate ($R_L \geq 5.0\text{ k}\Omega$)	S_R	—	0.1	—	V/ μs

* $T_{low} = 0^\circ\text{C}$ $T_{high} = +70^\circ\text{C}$

MC1776C

ELECTRICAL CHARACTERISTICS ($V_{CC} = +15\text{ V}$, $V_{EE} = -15\text{ V}$, $I_{set} = 15\text{ }\mu\text{A}$, $T_A = +25^\circ\text{C}$, unless otherwise noted.*)

Characteristic	Symbol	Min	Typ	Max	Unit
Input Offset Voltage ($R_S \leq 10\text{ k}\Omega$) $T_A = +25^\circ\text{C}$ $T_{low}^* \leq T_A \leq T_{high}^*$	V_{IO}	— —	2.0 —	6.0 7.5	mV
Offset Voltage Adjustment Range	V_{IOR}	—	18	—	mV
Input Offset Current $T_A = +25^\circ\text{C}$ $T_A = T_{high}$ $T_A = T_{low}$	I_{IO}	— — —	2.0 — —	25 25 40	nA
Input Bias Current $T_A = +25^\circ\text{C}$ $T_A = T_{high}$ $T_A = T_{low}$	I_{IB}	— — —	15 — —	50 50 100	nA
Input Resistance	r_i	—	5.0	—	M Ω
Input Capacitance	c_i	—	2.0	—	pF
Input Voltage Range $T_{low} \leq T_A \leq T_{high}$	V_{ID}	± 10	—	—	V
Large Signal Voltage Gain $R_L \geq 5.0\text{ k}\Omega$, $V_O = \pm 10\text{ V}$, $T_A = +25^\circ\text{C}$ $R_L \geq 75\text{ k}\Omega$, $V_O = \pm 10\text{ V}$, $T_{low} \leq T_A \leq T_{high}$	A_{VOL}	50 k 50 k	400 k —	— —	V/V
Output Voltage Swing $R_L \geq 5.0\text{ k}\Omega$, $T_A = +25^\circ\text{C}$ $R_L \geq 75\text{ k}\Omega$, $T_{low} \leq T_A \leq T_{high}$	V_O	± 10 ± 10	± 13 —	— —	V
Output Resistance	r_o	—	1.0	—	k Ω
Output Short Circuit Current	I_{SC}	—	12	—	mA
Common Mode Rejection $R_S \leq 10\text{ k}\Omega$, $T_{low} \leq T_A \leq T_{high}$	CMR	70	90	—	dB
Supply Voltage Rejection Ratio $R_S \leq 10\text{ k}\Omega$, $T_{low} \leq T_A \leq T_{high}$	PSRR	—	25	200	$\mu\text{V/V}$
Supply Current $T_A = +25^\circ\text{C}$ $T_{low} \leq T_A \leq T_{high}$	I_{CC} , I_{EE}	— —	160 —	190 200	μA
Power Dissipation $T_A = +25^\circ\text{C}$ $T_{low} \leq T_A \leq T_{high}$	P_D	— —	— —	5.7 6.0	μW
Transient Response (Unity Gain) $V_{in} = 20\text{ mV}$, $R_L \geq 5.0\text{ k}\Omega$, $C_L = 100\text{ pF}$ Rise Time Overshoot	t_{TLH} t_{os}	— —	0.35 10	— —	μs %
Slew Rate ($R_L \geq 5.0\text{ k}\Omega$)	S_R	—	0.8	—	V/ μs

* $T_{low} = 0^\circ\text{C}$ $T_{high} = +70^\circ\text{C}$

Figure 1. Set Current versus Set Resistor

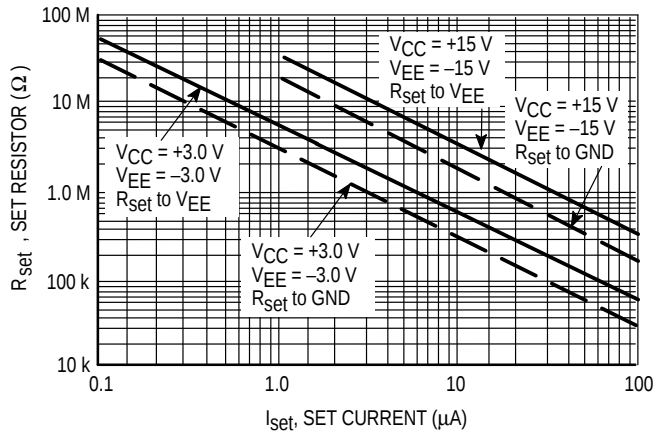


Figure 2. Positive Standby Supply Current versus Set Current

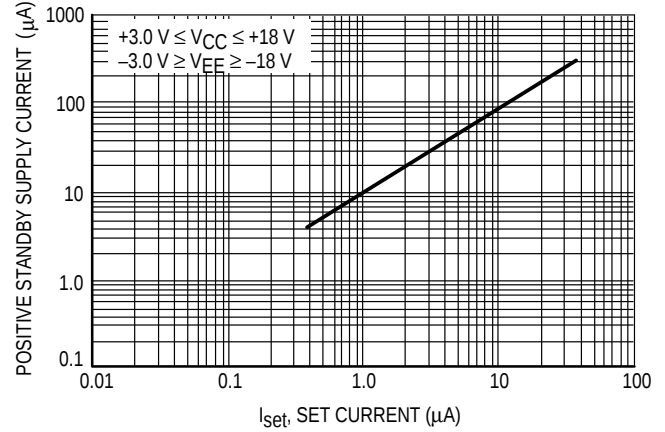


Figure 3. Open Loop Gain versus Set Current

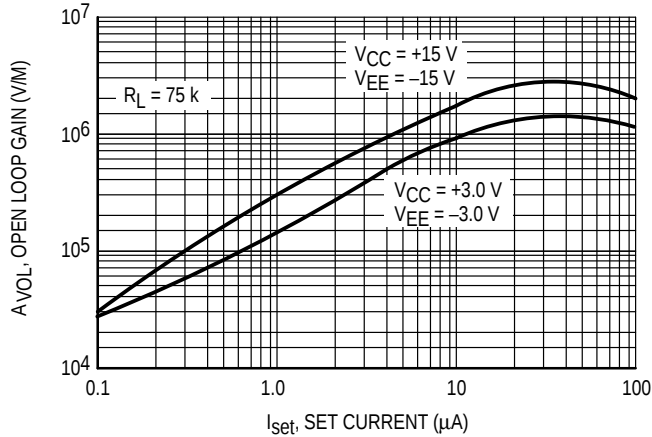


Figure 4. Input Bias Current versus Set Current

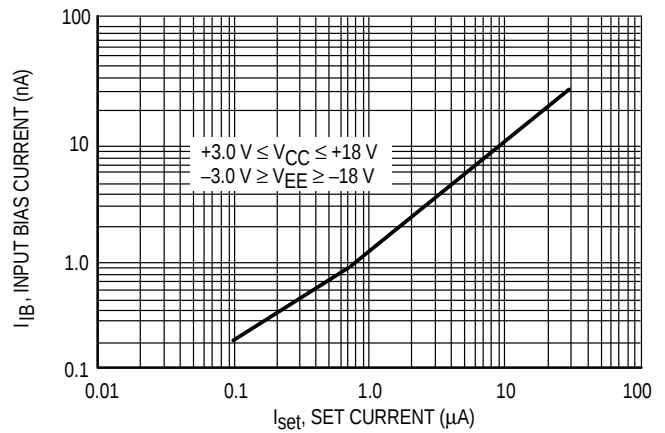


Figure 5. Input Bias Current versus Ambient Temperature

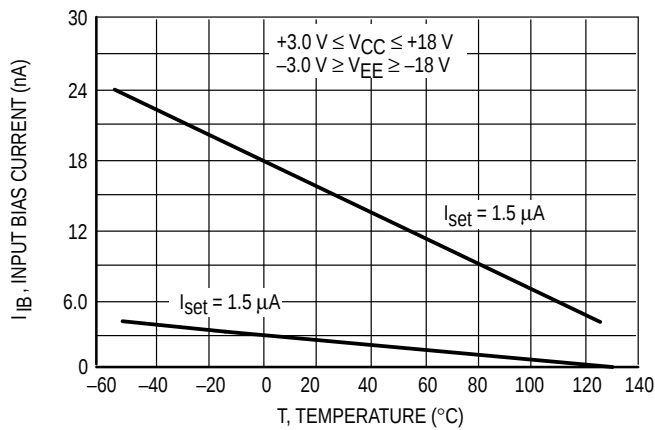


Figure 6. Gain Bandwidth Product versus Set Current

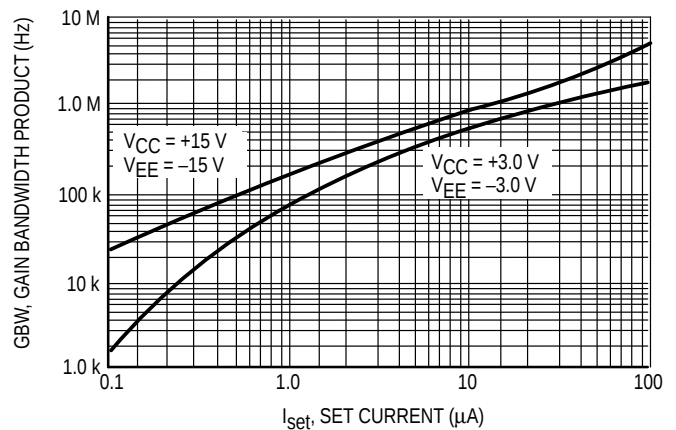


Figure 7. Output Voltage Swing versus Load Resistance

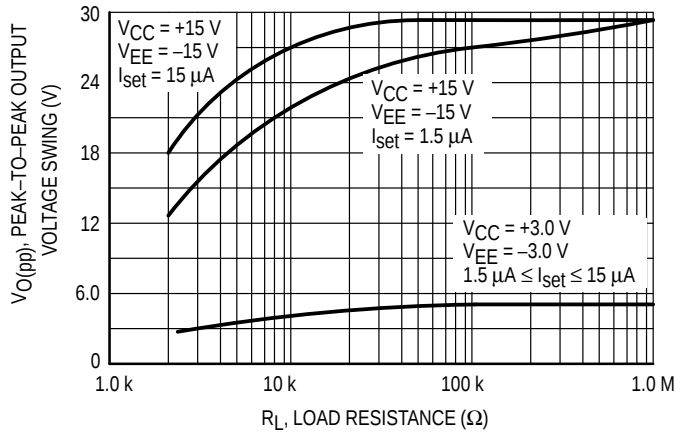


Figure 8. Supply Current versus Ambient Temperature

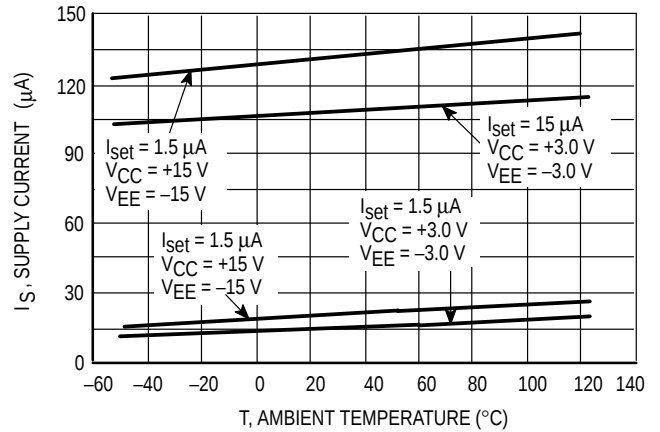


Figure 9. Output Voltage Swing versus Supply Voltage

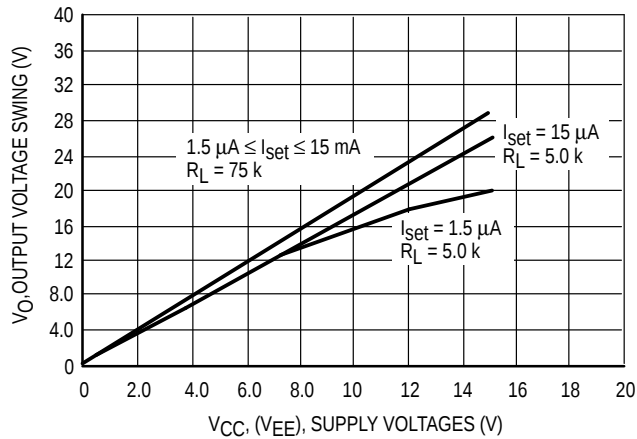


Figure 10. Slew Rate versus Set Current

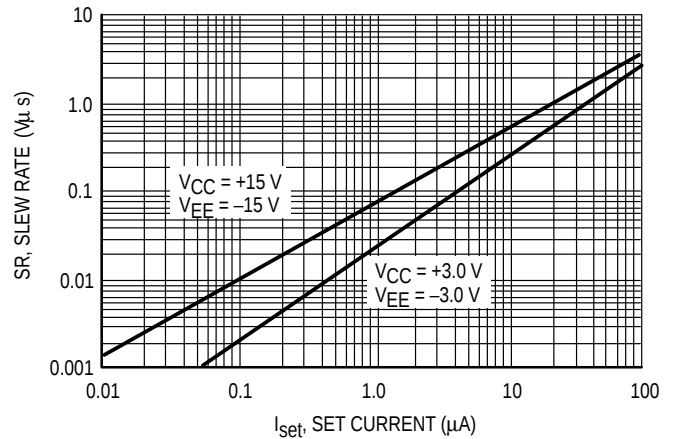


Figure 11. Input Noise Voltage versus Set Current

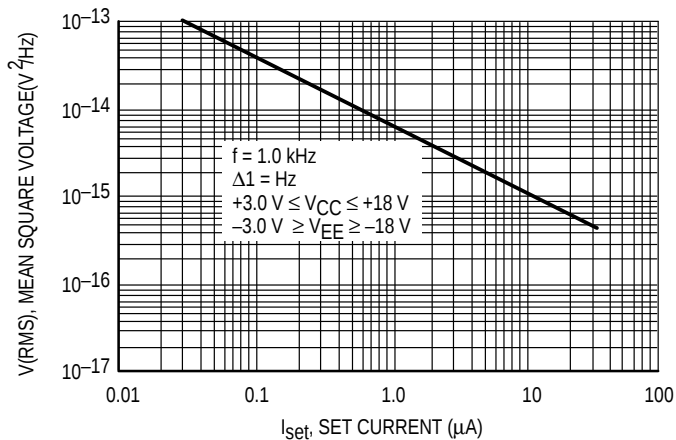


Figure 12. Optimum Source Resistance for Minimum Noise versus Set Current

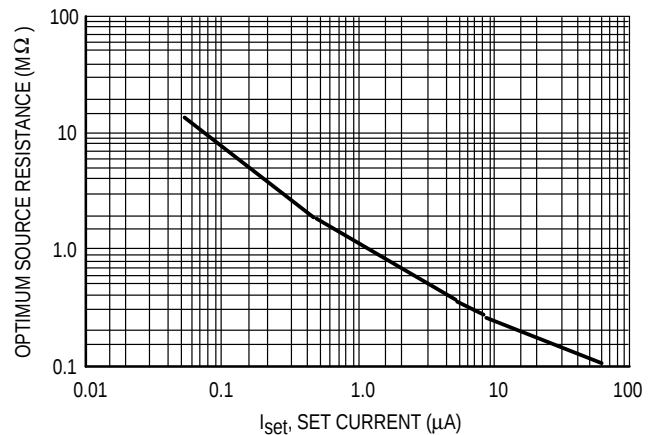
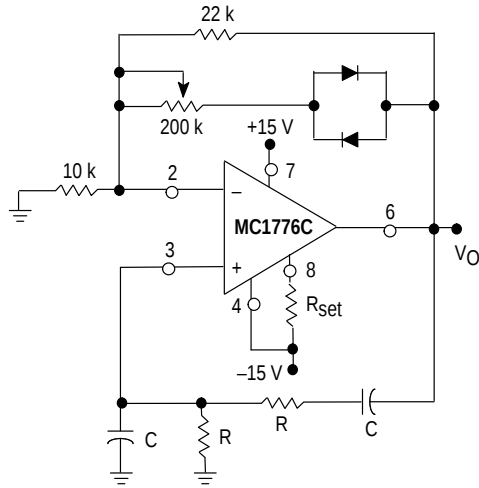


Figure 13. Wien Bridge Oscillator

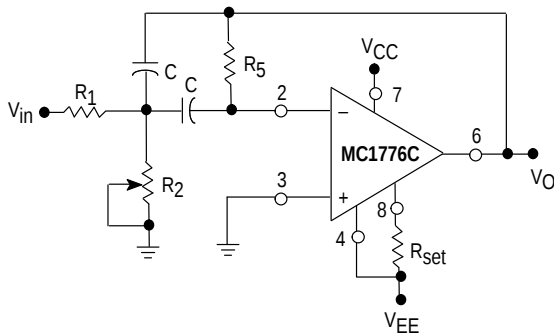


$$f_0 = \frac{1}{2\pi RC} \quad (\text{for } f_0 = 1.0 \text{ kHz})$$

$$R = 16 \text{ k}\Omega$$

$$C = 0.01 \mu\text{F}$$

Figure 14. Multiple Feedback Bandpass Filter



For a given:

f_0 = center frequency
 $A(f_0)$ = Gain at center frequency
 Q = quality factor

Choose a value for C, then

$$R_5 = \frac{Q}{\pi f_0 C}$$

$$R_1 = \frac{R_5}{2A(f_0)}$$

$$R_2 = \frac{R_1 R_5}{4Q^2 R_1 - R_5}$$

To obtain less than 10% error from the operational amplifier:

$$\frac{Q_0 f_0}{\text{GBW}} \leq 0.1$$

where f_0 and GBW are expressed in Hz. GBW is available from Figure 6 as a function of Set Current, I_{set} .

Figure 15. Multiple Feedback Bandpass Filter (1.0 kHz)

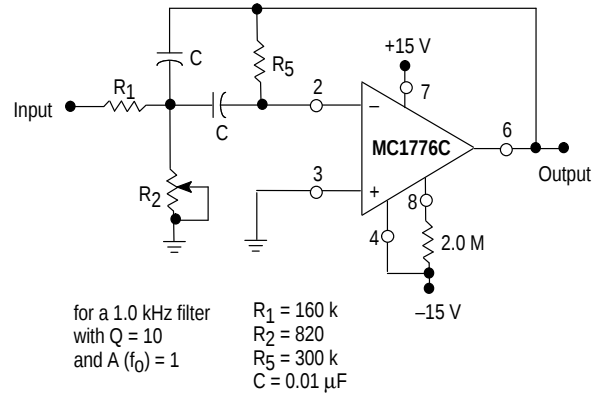


Figure 16. Gated Amplifier

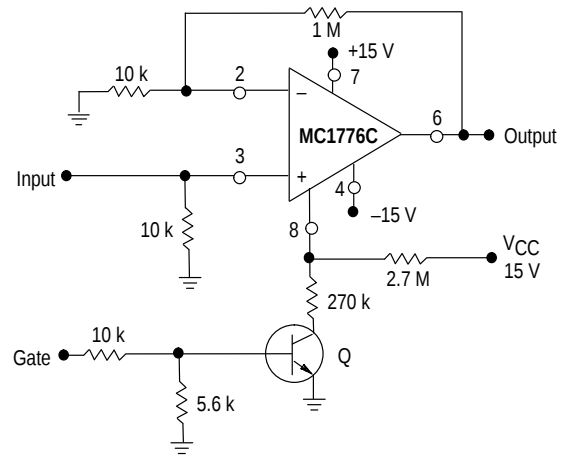
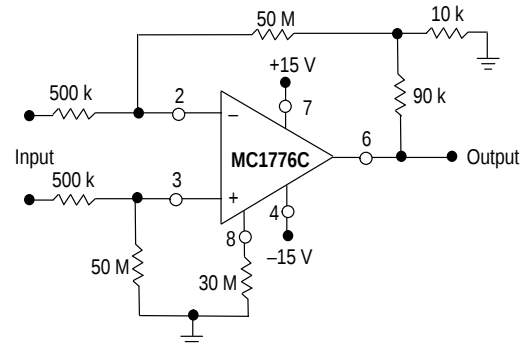


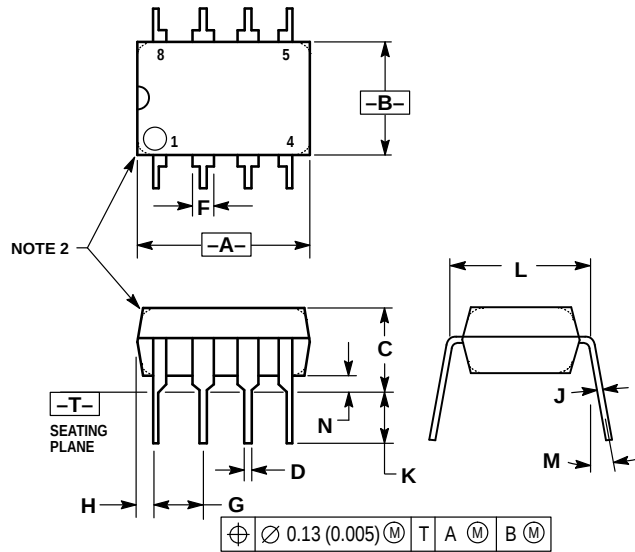
Figure 17. High Input Impedance Amplifier



MC1776C

OUTLINE DIMENSIONS

P1 SUFFIX PLASTIC PACKAGE CASE 626-05 ISSUE K

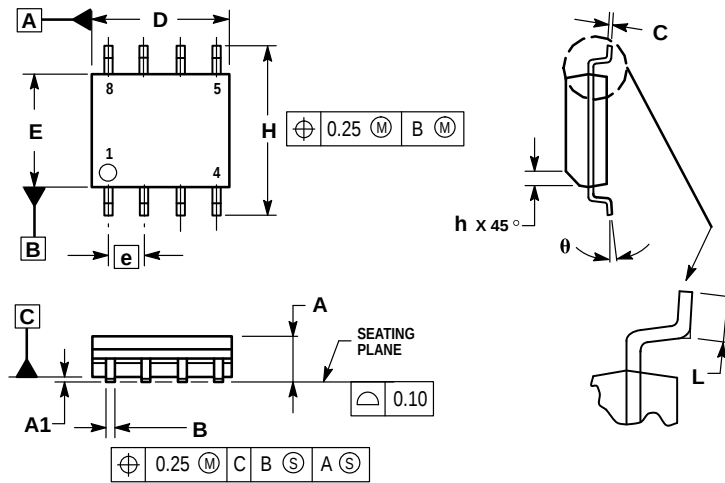


NOTES:

1. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
2. PACKAGE CONTOUR OPTIONAL (ROUND OR SQUARE CORNERS).
3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.40	10.16	0.370	0.400
B	6.10	6.60	0.240	0.260
C	3.94	4.45	0.155	0.175
D	0.38	0.51	0.015	0.020
F	1.02	1.78	0.040	0.070
G	2.54 BSC		0.100 BSC	
H	0.76	1.27	0.030	0.050
J	0.20	0.30	0.008	0.012
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300 BSC	
M	— 10°		— 10°	
N	0.76	1.01	0.030	0.040

D SUFFIX PLASTIC PACKAGE CASE 751-05 (SO-8) ISSUE R



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. DIMENSIONS ARE IN MILLIMETERS.
3. DIMENSION D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE MOLD PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS	
	MIN	MAX
A	1.35	1.75
A1	0.10	0.25
B	0.35	0.49
C	0.18	0.25
D	4.80	5.00
E	3.80	4.00
e	1.27 BSC	
H	5.80	6.20
h	0.25	0.50
L	0.40	1.25
θ	0°	7°

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